Supplementary Information

Structural Effects on Incident Photon-to-current Conversion Efficiency of Zn Porphyrin Dyes on the Low Index Planes of TiO_2

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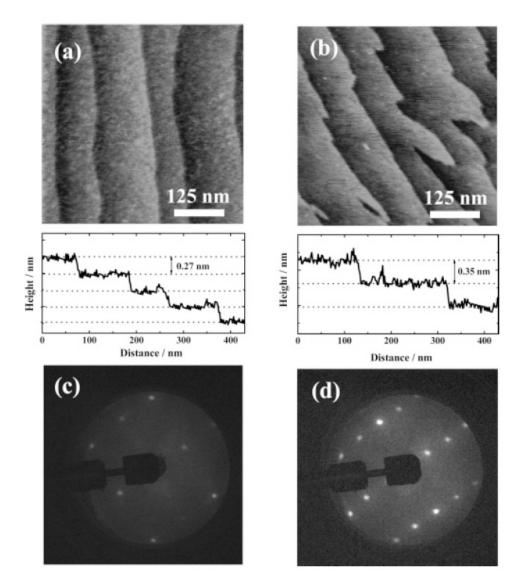


Figure S1 AFM images and LEED patterns of Nb doped TiO_2 single crystal surfaces after chemical etching in HF and annealing at 600° C in air. AFM images: (a) $TiO_2(100)$, (b) $TiO_2(110)$. LEED patterns: (c) $TiO_2(100)$, (d) $TiO_2(110)$. The figures are reproduced from ref. 38.

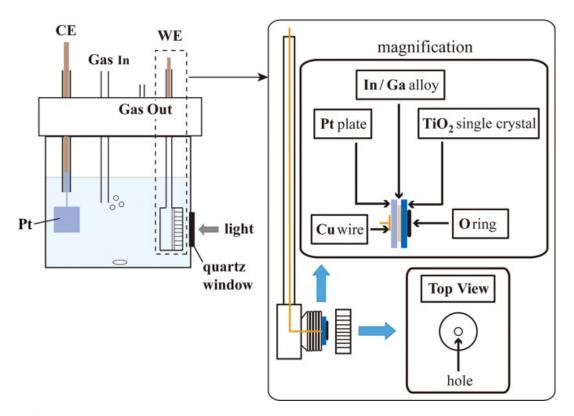


Figure S2 Illustration of the cell (left) and the holder of TiO_2 single crystal (right)